

NPN-Silizium-Fototransistor Silicon NPN Phototransistor

LPT 80 A



Wesentliche Merkmale

- Speziell geeignet für Anwendungen im Bereich von 470 nm bis 1080 nm
- Sidelooker im Kunststoffgehäuse
- Hohe Empfindlichkeit
- Passend zu IRED IRL 80 A, IRL 81 A

Anwendungen

- Fertigungs- und Kontrollanwendungen der Industrie
- Lichtschranken

Features

- Especially suitable for applications from 470 nm to 1080 nm
- Sidelooker in plastic package
- High sensitivity
- Matches IR emitter IRL 80 A, IRL 81 A

Applications

- A variety of manufacturing and monitoring applications
- Photointerrupters

Typ Type	Bestellnummer Ordering Code	Gehäuse Package
LPT 80 A	Q68000-A7852	Klares Kunststoffgehäuse, Lötspieße im 2.54-mm-Raster ($\frac{1}{10}$ "), Kollektorkennzeichnung: Längerer Lötspieß Clear plastic miniature package, 2.54 mm ($\frac{1}{10}$ ") lead spacing, collector marking: long solder lead

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{op}; T_{stg}$	- 40 ... + 100	°C
Kollektor-Emitterspannung Collector-emitter voltage	V_{CE}	30	V
Kollektorstrom Collector current	I_C	50	mA
Kollektorspitzenstrom, $\tau = 10 \mu s$ Collector surge current	I_{CS}	100	mA
Emitter-Kollektorspannung Emitter-collector voltage	V_{EC}	7	V
Verlustleistung, $T_A = 25 \text{ °C}$ Total power dissipation	P_{tot}	100	mW
Wärmewiderstand Thermal resistance	R_{thJA}	750	K/W

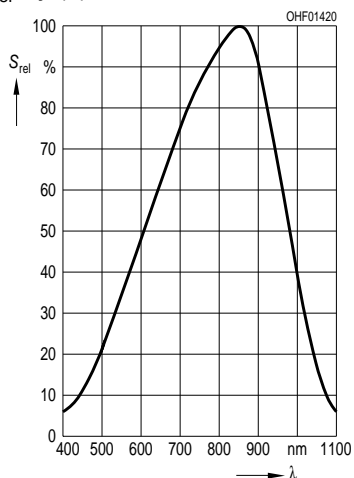
Kennwerte ($T_A = 25\text{ °C}$, $\lambda = 950\text{ nm}$)

Characteristics

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	$\lambda_{S\text{ max}}$	850	nm
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von S_{max} Spectral range of sensitivity $S = 10\%$ of S_{max}	λ	430 ... 1070	nm
Abmessung der Chip-Fläche Dimensions of chip area	$L \times B$ $L \times W$	0.55×0.55	mm \times mm
Halbwinkel Half angle	φ	± 35	Grad deg.
Kapazität, $V_{\text{CE}} = 5\text{ V}$, $f = 1\text{ MHz}$, $E = 0$ Capacitance	C_{CE}	3.3	pF
Dunkelstrom, $V_{\text{CE}} = 5\text{ V}$ Dark current	I_{R}	3 (< 50)	nA
Fotostrom Photocurrent $E_e = 0.5\text{ mW/cm}^2$, $V_{\text{CE}} = 5\text{ V}$, $\lambda = 950\text{ nm}$ $E_v = 1000\text{ lx}$, Normlicht/standard light A, $V_{\text{CE}} = 5\text{ V}$	I_{PCE} I_{PCE}	> 0.25 3.2	mA
Anstiegs- und Abfallzeit Rise and fall time $R_L = 1\text{ k}\Omega$, $V = 5\text{ V}$, $\lambda = 950\text{ nm}$, $I_C = 1\text{ mA}$	t_r, t_f	10	μs
Kollektor-Emitter-Sättigungsspannung Collector-emitter saturation voltage $I_C = I_{\text{PCE min}} \times 0.8$, $E_e = 0.5\text{ mW/cm}^2$	V_{CEsat}	150	mV

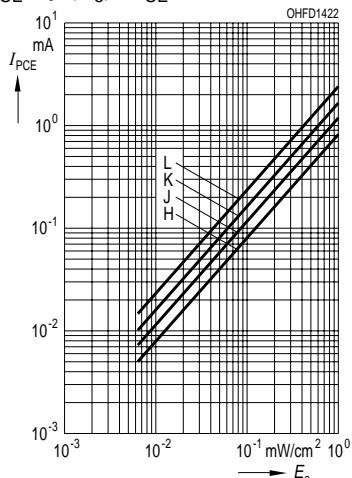
Relative Spectral Sensitivity

$S_{rel} = f(\lambda)$



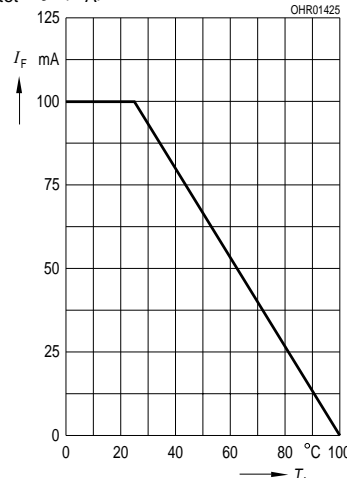
Photocurrent

$I_{PCE} = f(E_e), V_{CE} = 5 V$



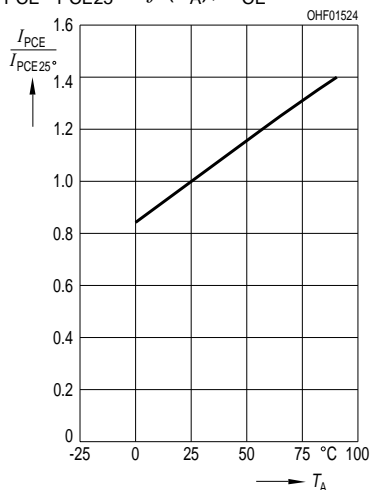
Total Power Dissipation

$P_{tot} = f(T_A)$



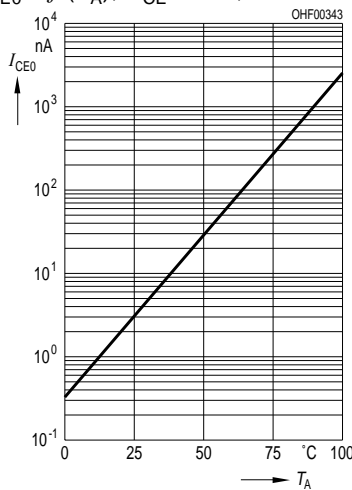
Photocurrent

$I_{PCE}/I_{PCE25^\circ} = f(T_A), V_{CE} = 5 V$



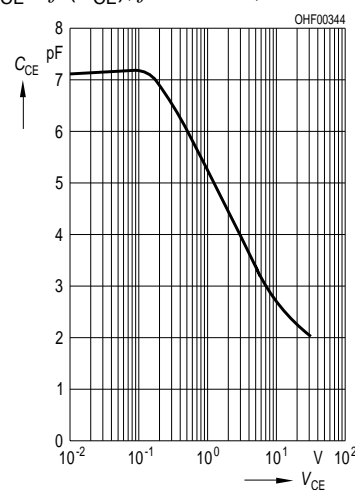
Dark Current

$I_{CE0} = f(T_A), V_{CE} = 5 V, E = 0$



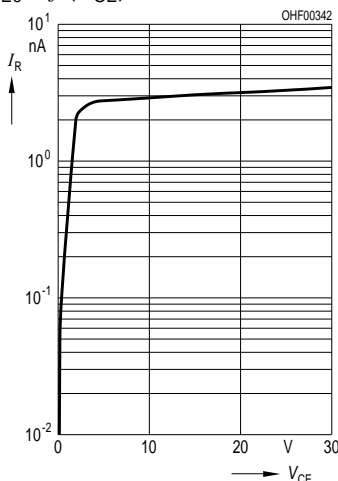
Capacitance

$C_{CE} = f(V_{CE}), f = 1 MHz, E = 0$



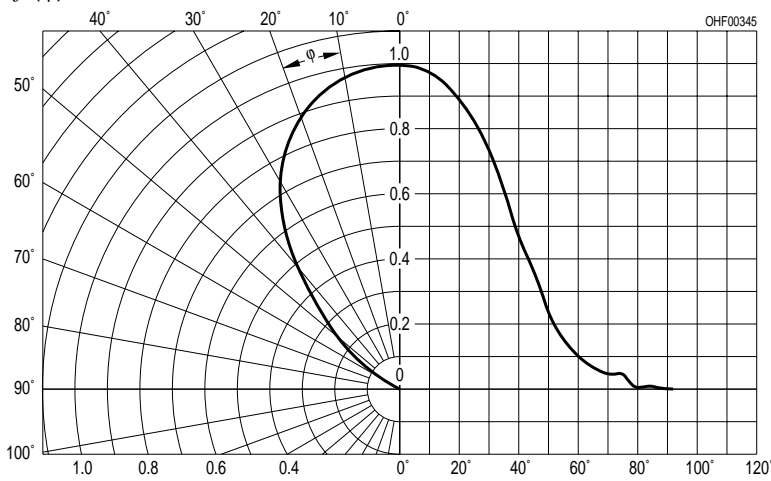
Dark Current

$I_{CE0} = f(V_{CE}), E = 0$

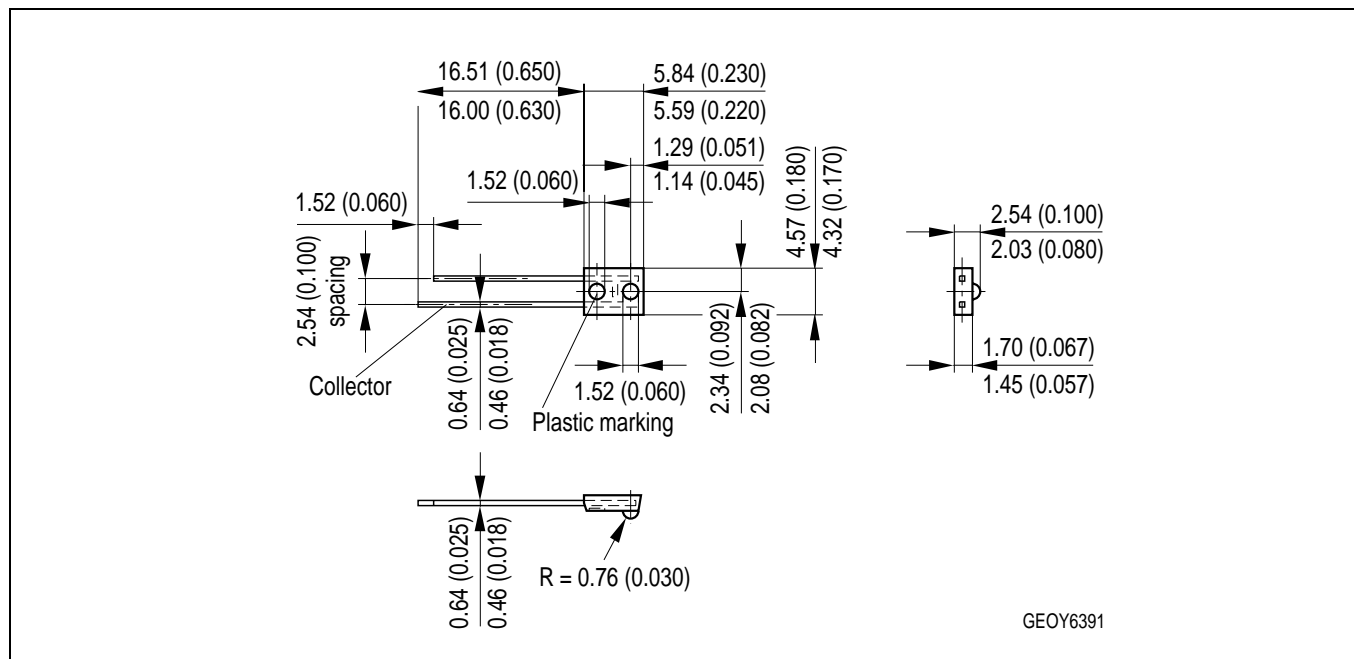


Directional Characteristics

$S_{rel} = f(\phi)$



Maßzeichnung Package Outlines



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

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Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

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